



⑪ Publication number : **0 447 077 A2**

⑫ **EUROPEAN PATENT APPLICATION**

⑲ Application number : **91301705.9**

⑤① Int. Cl.⁵ : **G02F 1/136, G09G 3/36**

⑳ Date of filing : **01.03.91**

③① Priority : **09.03.90 JP 59090/90**

④③ Date of publication of application :
18.09.91 Bulletin 91/38

⑥④ Designated Contracting States :
DE FR GB IT

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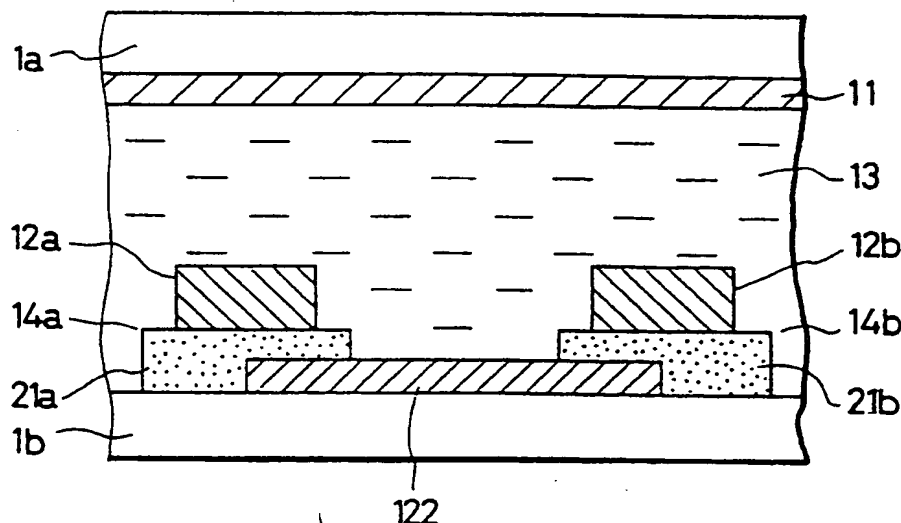
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⑤④ **Electro-optical device.**

⑤⑦ An electro-optical device according to the invention comprises opposed substrates (1a, 1b), a material (13) having an electro-optical effect between the two substrates, row electrodes (11) formed on one of the substrates, column electrodes (12) formed on the other of the substrates, and pixel electrodes (122) arranged in a matrix on at least one of the substrates. Each pixel electrode is connected to a first row, or column, electrode (12a) through a first non-linear resistance element (14a) and to a second row, or column, electrode (12b) through a second non-linear resistance element (14b). The resistance of each of the first and second non-linear resistance elements is thus controlled by the first and second row, or column, electrodes for providing a stable and reliable operation.

FIG. 1B



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ELECTRO-OPTICAL DEVICE

The present invention relates to an electro-optical device, and especially to an electro-optical device in the form of an active matrix display panel wherein each unit pixel includes a pixel electrode and an associated non-linear resistance element.

A liquid crystal display panel has the advantages of being a thin, light weight display panel having low power consumption. Such panels are currently used in a variety of applications, especially in lap top or book type personal computers. Amongst the conventional liquid crystal display panels, active matrix display panels have received a great deal of attention in view of their high resolution, and high image quality.

Typical active elements employed in such panels are a three terminal element using a thin film transistor, a two terminal element represented by a non-linear resistance element (e.g. a metal-insulator-metal (MIM) resistance element), and a p-n junction thin film diode. However, these conventional active elements suffer from various drawbacks.

The three terminal element is produced by means of a complicated fabrication process, so that a low yield and high cost are inevitable. And the diode mentioned above has a low break down voltage and is susceptible to static electricity.

By contrast, the non-linear resistance element has a simple structure and a high break down voltage of 25 V or more. Therefore, the non-linear resistance element is preferable for a display panel having a large area produced at low cost.

A conventional electro-optical device using non-linear resistance elements is shown in Figures 2A to 2C with Figure 2A being a circuit diagram showing an X-Y matrix panel circuit of the device, Figure 2B being a sectional view showing the structure of a unit cell of the device, and Figure 2C being a plan view showing the structure of one of the non-linear resistance elements.

Referring to Figures 2A to 2C, a plurality, namely one hundred to one thousand, of row electrodes 1 and a plurality, namely one hundred to one thousand, of column electrodes 2 are generally formed on opposed substrates A and B, respectively. At each X-Y intersection, a pixel electrode 22 and a non-linear resistance layer 21, constituting a non-linear resistance element 4, are connected to a corresponding one of the column electrodes 2. An electro-optical material 3 is sealed between the substrates A and B. When this structure is used as a liquid crystal display panel, the substrates A and B are generally made of glass, the row and pixel electrodes 1 and 22 are generally made of indium tin oxide (ITO), the column electrode 2 is generally made of Cr or Al, and the non-linear resistance layer 21 is generally made of Si-rich silicon nitride.

Operation of this type of liquid crystal display panel is as follows. The row electrodes 1 (or column electrodes 2) in Figures 2A to 2C are sequentially selected one by one, and data is written by applying a voltage to each corresponding column electrode 2 (or row electrode 1) in the selection period.

In order to provide a display with a sufficient contrast ratio (e.g. a contrast ratio of 10:1 or more), a root-mean-square (RMS) voltage applied to the liquid crystal material at a selected pixel must be higher than a saturation voltage of the liquid crystal material, and an RMS voltage applied to the liquid crystal material at a non-selected pixel must be lower than a threshold voltage of the liquid crystal material. The non-linear resistance element 4 has characteristics defined such that the resistance of the element changes exponentially with the voltage applied thereto. For this reason, a higher voltage is arranged to be applied to the non-linear resistance element 4 of a selected pixel within a selection period to decrease the element resistance (e.g. to $10^8 \Omega$ or less), so that a charge can easily be injected into the pixel electrode 22. At a half selected pixel, a voltage applied to the nonlinear resistance element 4 is suppressed to be low within the selection period. In this case, the resistance of the element is not decreased (e.g. being $10^9 \Omega$ or more), and charge tends not to be injected into the pixel electrode 22. During a retention period, a low voltage is applied to the non-linear resistance elements 4 of both the selected and the non-selected pixels, and the resistance of the non-linear resistance elements is kept high (e.g. being $10^{11} \Omega$ or more), thereby increasing the charge retention capacity of each element.

As is apparent from the above description, when the non-linear resistance element is used, the RMS voltage applied to the liquid crystal material can be kept higher than the saturation voltage of the liquid crystal material at the selected pixels and lower than the threshold voltage at the non-selected pixels. Therefore, a high contrast ratio can be obtained even if the number of dots is increased.

In order to provide a display on such a liquid crystal display panel, it is important to determine the driving voltage, the composition and thickness of the non-linear resistance layer 21, and the structure of the non-linear resistance element 4 so as to obtain a desired resistance for the non-linear resistance element 4 during the selection and retention periods. It is also important to increase the ratio of the capacitance C_{LC} of the liquid crystal section of each pixel to the capacitance C_1 of the non-linear resistance element 4 of each pixel (to be at least $C_{LC}/C_1 \geq 5$) so as to obtain a sufficient operating margin and to compensate for a distribution of element characteristics and their deviation over time.

Although the above display panel using non-linear resistance elements can have a large capacity, a problem arises if a grey scale display is to be produced in addition to a simple on/off display, especially by comparison with a display panel using three terminal elements. This is for the following reason.

Since each three terminal element is operated as a perfectly independent switch, a given charge injected into one pixel is rarely influenced by a charge written in another pixel during a period of retention of the given charge. In the case of the non-linear resistance element, however, a very small current (up to about 10 pA) flows even during the retention period. Data stored in other pixels gradually influences data stored in each respective pixel throughout the corresponding column electrodes (or row electrodes). For this reason, the RMS voltage applied to the liquid crystal material in accordance with a display pattern gradually deviates from the pre-determined value. In addition, since the resistance of the element greatly influences the charge injection capacity and the charge retention capacity, element characteristics vary over the panel surface and shift as a result of deterioration with time. These changes in element characteristics cause a direct change in the RMS voltage applied to the liquid crystal material. For this reason, when an RMS voltage applied to the liquid crystal material has to be controlled with high precision, as in a multi-level grey scale display, a contrast variation results, making it difficult to provide a normal display. This variation increases when the panel size is increased and when the number of dots is increased, which is a nuisance.

It is an object of the present invention to provide an electro-optical device in which the above problems are avoided or reduced.

The invention provides an electro-optical device wherein a plurality of non-linear resistance elements form a unit with each pixel electrode, and wherein each pixel electrode is connected independently through the respective non-linear resistance elements to a corresponding plurality of row, or column, electrodes. The resistance of the non-linear resistance elements may then be controlled using the row, or column, electrodes to provide a stable operation against variation in the characteristics of the non-linear resistance elements and deterioration over time. Further, the data input to one pixel may be free of adverse effect from the data input to other pixels.

In accordance with the present invention there is provided an electro-optical device comprising opposed substrates, a material having an electro-optical effect between the two substrates, row electrodes formed on one of the substrates, column electrodes formed on the other of the substrates, and pixel electrodes arranged in a matrix on at least one of the substrates, characterised in that each pixel electrode is connected to a first row, or column, electrode through

a first nonlinear resistance element and to a second row, or column, electrode through a second non-linear resistance element, and in that the resistances of the first and second non-linear resistance elements are controlled by the first and second row, or column, electrodes.

In operation, a signal may be applied to the first and second row, or column, electrodes to control the resistances of the first and second non-linear resistance elements to cause these elements to serve as a switch, and thereby to suppress variation in charge injection amounts caused by non-uniform characteristics and deterioration over time of the non-linear resistance elements. At the same time, variation in leakage amount may be suppressed to allow accurate control of the RMS voltage.

The invention enables a stable, accurate, high quality display, such as a grey scale display, to be obtained in a panel using non-linear resistance elements.

Furthermore, an improved data writing capacity and uniform display characteristics are features of the invention, even when there is a distribution in element characteristics or deterioration occurs over time.

As described below, the present invention enables data retention capacity to be improved and provides a stable and arbitrary display regardless of the type of pattern to be displayed.

The present invention will be described further, by way of example, with reference to the accompanying drawings, in which:-

Figure 1A is a circuit diagram of an X-Y matrix panel of an electro-optical device according to an embodiment of the present invention;

Figure 1B is a sectional view showing the structure of a unit cell of the electro-optical device shown in Figure 1A;

Figure 1C is a plan view showing the structure and arrangement of non-linear resistance elements of the electro-optical device shown in Figure 1A;

Figure 2A is a circuit diagram of an X-Y matrix panel of a conventional electro-optical device;

Figure 2B is a sectional view showing the structure of a unit cell of the conventional electro-optical device shown in Figure 2A;

Figure 2C is a plan view showing the structure of a non-linear resistance element of the electro-optical device shown in Figure 2A; and

Figures 3A to 3F are signal wave forms for explaining the operation of the electro-optical device shown in Figures 1A to 1C.

An embodiment of the present invention will now be described in detail with reference initially to Figures 1A to 1C. As shown, an electro-optical device according to the present invention has a plurality of pixel electrodes 122 formed on a substrate 1b. These electrodes are formed by depositing, e.g. ITO film, by

sputtering, and by selectively etching the deposited ITO film. Non-linear resistance layers 21a and 21b, e.g. Si-rich SiNx, and operating electrodes 12a and 12b, e.g. Cr, are continuously deposited in the order named, and are continuously etched to connect each pixel electrode 122 to a first operating electrode, 12a, through a first non-linear resistance element, 14a, and to a second operating electrode, 12b, through a second non-linear resistance element, 14b. A counter electrode 11, e.g. ITO film, is formed on a counter substrate 1a. An electro-optical material, 13, e.g. a liquid crystal material, is sealed between the counter substrate 1a and the substrate 1b.

The electro-optical device thus formed operates as follows. Each pair of the operating electrodes 12 in Figure 1A, of which there are a large number, is sequentially selected, and data is written to the associated pixels by the respective counter electrodes 11 within the selection period. Figures 3A to 3F show the signals applied to the electrodes, in which Figure 3A shows an input wave form for the first operating electrode 12a, and Figure 3B shows an input wave form for the second operating electrode 12b. Input waveforms for the counter electrode 11 are shown in Figures 3C to 3F. Referring to Figure 3A, the potential of the operating electrode 12a is kept at V_0 in a non-selected state but at $V_0 + V_{OP}$ in a selected state. Referring to Figure 3B, the potential of the operating electrode 12b is kept at V_0 in a non-selected state but at $V_0 - V_{OP}$ in a selected state. Since the two non-linear resistance elements 14a and 14b are located very close to each other, their characteristics may be regarded as being identical. The potential of the pixel electrode 122 is always kept at about V_0 . The voltages applied to each of the non-linear resistance elements are very close to V_0 and V_{OP} in the non-selected and selected states, respectively. When a sufficiently high voltage (e.g. a voltage which causes the resistance of the element to be $10^8 \Omega$ or less) is selected for the voltage V_{OP} , each non-linear resistance element has a low resistance ($10^8 \Omega$ or less) in the selected state and a high resistance ($10^{12} \Omega$ or more) in the non-selected state. In this manner, the non-linear resistance elements can be made to operate as a perfect switch.

Figures 3C, 3D, 3E and 3F show input wave forms for the counter electrode for data patterns to be written in all the pixels aligned along one counter electrode. Figure 3C shows a case wherein all the pixels are selected, Figure 3D shows a case wherein none of the pixels is selected, Figure 3E shows a case wherein one pixel is selected and the remaining pixels are not selected, and Figure 3F shows a case wherein one pixel is not selected and the remaining pixels are all selected.

During a selection period, each non-linear resistance element has a low resistance ($10^8 \Omega$ or less) as mentioned above. As a result of charge injection, a

voltage applied to the electro-optical material 13 is V_{ON} when the corresponding pixel is selected. A voltage applied to the electro-optical material 13 is V_{OFF} when the corresponding pixel is not selected. Data inversion is performed for every cycle to prevent the electro-optical material 13 from characteristic degradation by a DC bias when the electro-optical material 13 consists of a liquid crystal material.

The charge stored in the pixel electrode 122 during the selection period is not easily discharged regardless of changes in the potential of the counter electrode 11 since the non-linear resistance elements are kept in a high resistance state ($10^{12} \Omega$ or more) during a charge retention period. An RMS voltage applied to the electro-optical material 13 is mostly determined by counter electrode data stored during the selection period, and the influence of input data applied to other pixels can be substantially reduced. The fact that the RMS voltage applied to the electro-optical material 13 is determined in accordance with the counter electrode data indicates that the operation of the device does not depend much on the characteristics of the non-linear resistance elements. This is for the following reason. Since charge injection and retention only need be performed by the non-linear resistance elements, the voltage V_{OP} is selected to have a value sufficient to set the resistances of all the elements to be $10^8 \Omega$ or less. Under this condition, even if variation or deterioration occurs in the element characteristics over time, their resistances can be set to be values low enough to perform write access sufficiently. In this manner, each non-linear resistance element can be reliably operated as a switch.

The non-linear resistance element used in the present invention may comprise: amorphous silicon, silicon nitride, silicon oxide, silicon carbide or silicon oxynitride, whose silicon content is larger than a stoichiometric ratio. Such non-linear resistance elements may contain hydrogen, or at least one of phosphorus and boron.

As has been described above, according to the present invention, a plurality of non-linear resistance elements are formed on each pixel electrode and are operated by a pair of operating electrodes adjacent to each pixel electrode, so that the non-linear resistance elements can have a highly reliable switching function. Therefore, fine adjustment of each pixel can be stably effected. The potential level of each pixel electrode can be stabilised during a selection period and control by a data signal for accurate display of grey scale levels is facilitated. In practice, even if $\pm 20\%$ variation occurs in the characteristics of the non-linear resistance elements, it may be confirmed that RMS voltages applied to the liquid crystal material still fall within the range of ± 0.1 V of the desired values for all display patterns.

Claims

1. An electro-optical device comprising opposed substrates (1a, 1b), a material (13) having an electro-optical effect between the two substrates, row electrodes (11) formed on one of the substrates, column electrodes (12) formed on the other of the substrates, and pixel electrodes (122) arranged in a matrix on at least one of the substrates, characterised in that each pixel electrode is connected to a first row, or column, electrode (12a) through a first non-linear resistance element (14a) and to a second row, or column, electrode (12b) through a second non-linear resistance element (14b), and in that the resistances of the first and second non-linear resistance elements are controlled by the first and second row, or column, electrodes. 5 10 15
2. A device according to claim 1 characterised in that each non-linear resistance element comprises a layer essentially consisting of a material selected from the group including: amorphous silicon, silicon nitride, silicon oxide, silicon carbide and silicon oxynitride, whose silicon content is larger than a stoichiometric ratio. 20 25
3. A device according to claim 1 or 2 characterised in that each non-linear resistance element comprises a layer containing at least one of hydrogen, phosphorus and boron. 30
4. An electro-optical device characterised by two opposed substrates (1a, 1b), a material (13) having an electro-optical effect and sealed between said two opposed substrates, a large number of row electrodes (11) formed on one of said two opposed substrates, a large number of column electrodes (12) formed on the other of said two opposed substrates, and pixel electrodes (122) arranged in a matrix form on at least one of said two opposed substrates, and non-linear resistance elements (14) arranged in a matrix form on at least one of said two opposed substrates, wherein a plurality of the non-linear resistance elements (14a, 14b) are formed on each of said pixel electrodes, said each pixel electrode is connected to a first row, or column, electrode (12a) through a first non-linear resistance element (14a) and to a second row, or column, electrode (12b) through a second non-linear resistance element (14b), and said pair of first and second non-linear resistance elements are controlled by said pair of first and second row, or column, electrodes. 35 40 45 50 55

FIG. 1A

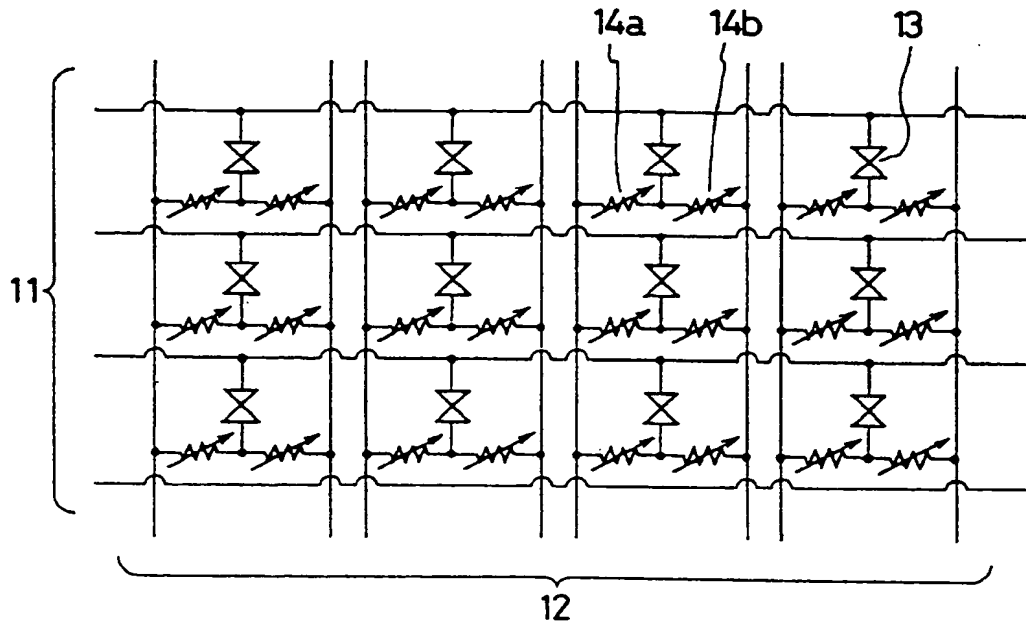


FIG. 1B

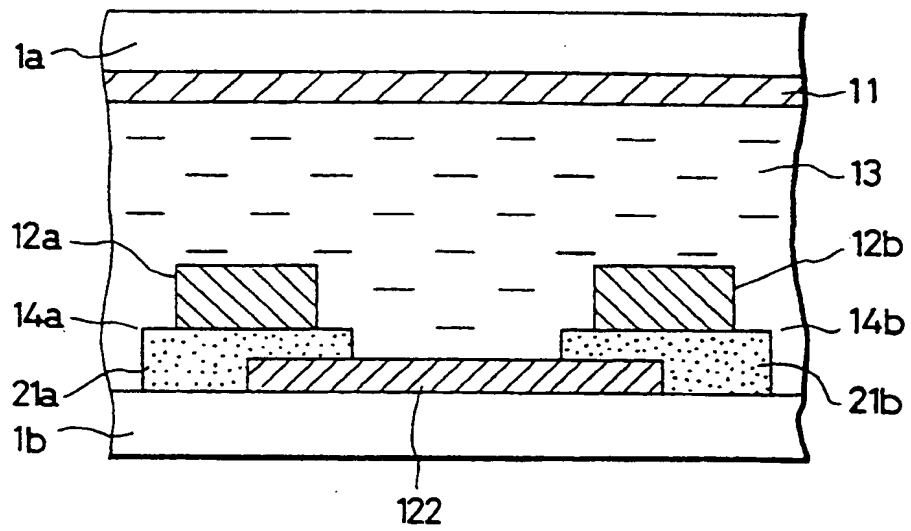


FIG. 1C

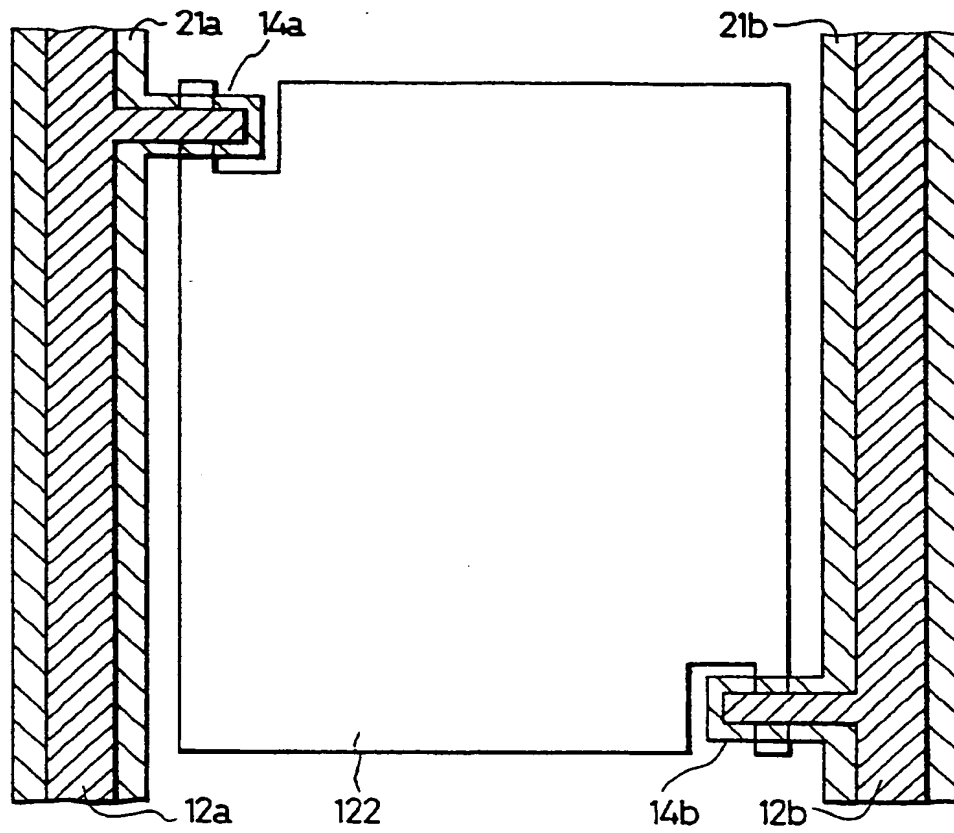


FIG. 2A PRIOR ART

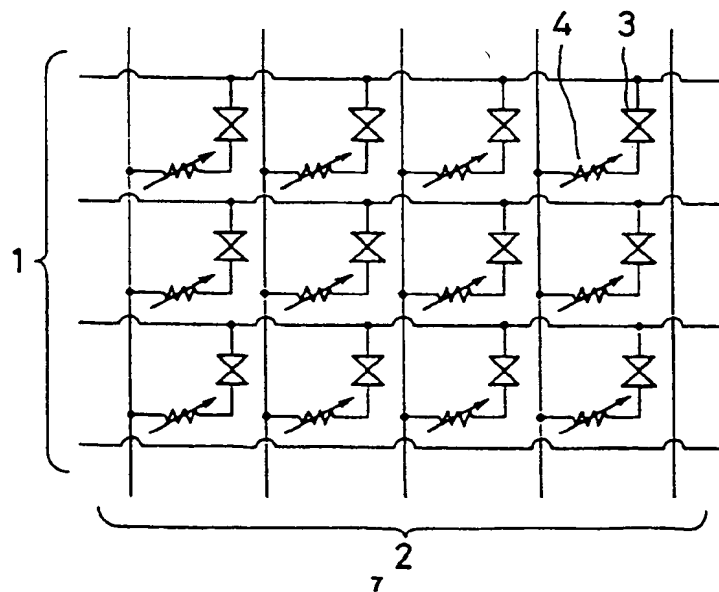


FIG. 2B PRIOR ART

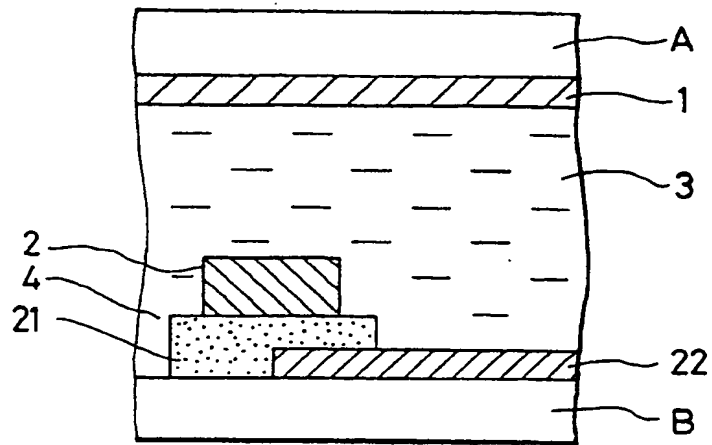


FIG. 2C PRIOR ART

